

Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 20 to 200 V

Forward Current - 5 A

FEATURES

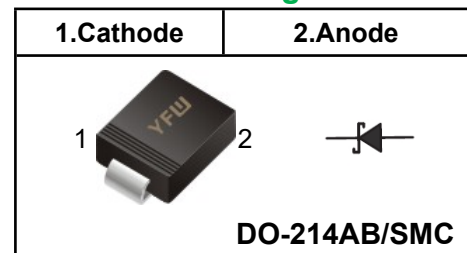
- ◆Metal silicon junction, majority carrier conduction
- ◆For surface mounted applications
- ◆Low power loss, high efficiency
- ◆High forward surge current capability
- ◆For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- ◆Case: DO-214AB/SMC
- ◆Terminals: Solderable per MIL-STD-750, Method 2026
- ◆Approx. Weight: 0.22g / 0.0077oz

Absolute Maximum Ratings and Electrical characteristics
Ratings at 25 °C ambient temperature unless otherwise specified.Single phase, half wave,
60Hz resistive or inductive load,for capacitive load, derate by 20 %

Pinning



Marking Code

SS52C	YFW SS52
SS54C	YFW SS54
SS56C	YFW SS56
SS58C	YFW SS58
SS510C	YFW SS510
SS512C	YFW SS512
SS515C	YFW SS515
SS520C	YFW SS520

Parameter	Symbols	SS52C	SS54C	SS56C	SS58C	SS510C	SS512C	SS515C	SS520C	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	40	60	80	100	120	150	200	V
Maximum RMS voltage	V_{RMS}	14	28	42	56	70	84	105	140	V
Maximum DC Blocking Voltage	V_{DC}	20	40	60	80	100	120	150	200	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	5.0								A
Peak Forward Surge Current,8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	120								A
Peak Forward Surge Current,1.0ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	240								A
I^2t Rating for fusing (3ms≤t≤8.3ms)	I^2t	59.7								A ² S
Maximum Instantaneous Forward Voltage at 5 A	V_F	0.55	0.70	0.85	0.95					V
Maximum Instantaneous Reverse Current at Rated DC Reverse Voltage T _A = 25°C T _A = 100°C	I_R	1.0 50								mA
Typical Junction Capacitance ⁽¹⁾	C_j	270	220	160	100		80			pF
Typical Thermal Resistance ⁽²⁾	R _{θJA} R _{θJC} R _{θJL}	100 20 25								°C/W
Operating Junction Temperature Range	T _j	-55 ~ +150								°C
Storage Temperature Range	T _{stg}	-55 ~ +150								°C

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

Fig.1 Forward Current Derating Curve

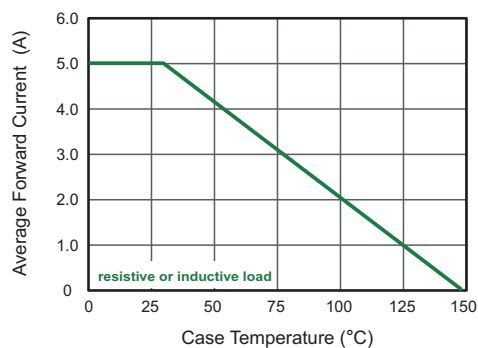


Fig.2 Typical Reverse Characteristics

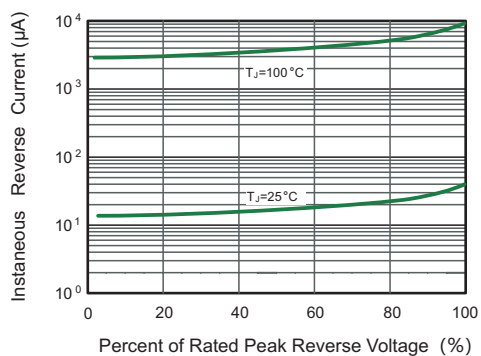


Fig.3 Typical Forward Characteristic

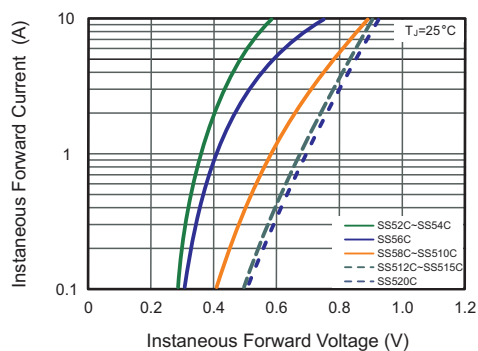


Fig.4 Typical Junction Capacitance

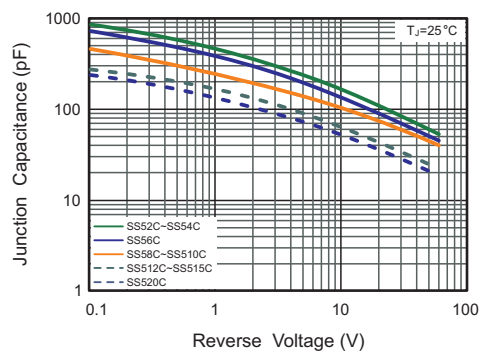
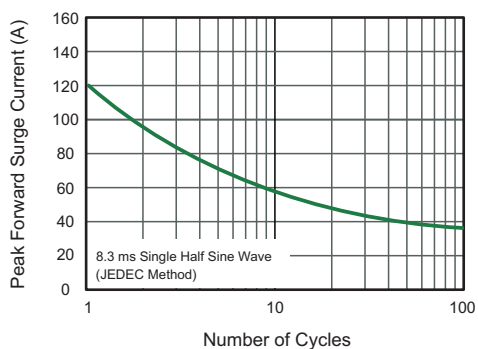
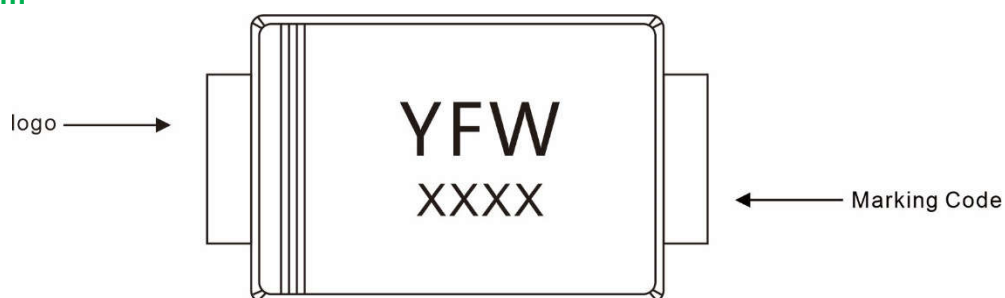


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current



Marking Diagram



Ordering information

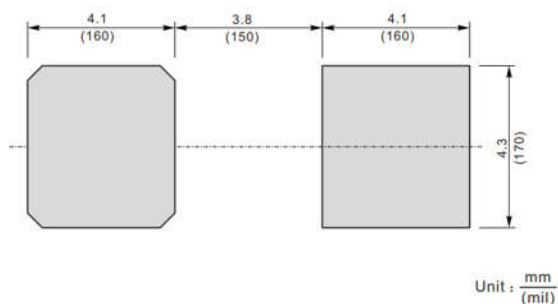
Package	Packing Description	Packing Quantity
DO-214AB SMC	Tape/Reel, 13"reel	3000PCS/Reel 30000PCS/Carton

Package Dimensions

DO-214AB SMC

Dim.	Millimeter(mm)		mil	
	Min.	Max.	Min.	Max.
A	2.00	2.62	79	103
E	6.5	7.0	256	276
D	5.6	6.2	220	244
E ₁	7.6	8.0	299	315
A ₁	0.05	0.21	2.0	8.3
C	0.15	0.31	5.9	12
L	0.9	1.6	35	63
b	2.75	3.25	108	128

The recommended mounting pad size



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